L Number	Hits	Search Text	DB	Time stamp
1	17	equalizer and embed\$5 and 333/\$.ccls.	USPAT;	2003/08/24
			US-PGPUB;	13:39
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
2	103	equalizer and (substrate layer) and	USPAT;	2003/08/24
		333/\$.ccls.	US-PGPUB;	13:41
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
3	5	equalizer same ((substrate layer) and	USPAT;	2003/08/24
		embed\$7)	US-PGPUB;	13:43
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
4	1312	coupler same embed\$7	USPAT;	2003/08/24
			US-PGPUB;	13:43
			EPO; JPO;	
		·	DERWENT;	
			IBM_TDB	
5	687	coupler with embed\$7	USPAT;	2003/08/24
			US-PGPUB;	13:43
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
6	31	(coupler with embed\$7) and 333/\$.ccls.	USPAT;	2003/08/24
			US-PGPUB;	13:44
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	19	coupler.ti. and varactor and capacit\$5	USPAT;	2003/08/22
			US-PGPUB;	12:32
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	•.
-	55750	coupled adj2 (line conductor trace	USPAT;	2003/08/22
	·	microstrip stripline path)	US-PGPUB;	12:35
			EPO; JPO;	•
			DERWENT;	
			IBM_TDB	
-	99	(coupled adj2 (line conductor trace	USPAT;	2003/08/22
Ì		microstrip stripline path)) and coupled adj2	US-PGPUB;	12:54
		(line conductor trace microstrip stripline	EPO; JPO;	
		path) with varactor	DERWENT;	
			IBM_TDB	
• ·	20	((coupled adj2 (line conductor trace	USPAT;	2003/08/22
		microstrip stripline path)) and coupled adj2	US-PGPUB;	12:36
		(line conductor trace microstrip stripline	EPO; JPO;	
		path) with varactor) and pin	DERWENT;	
			IBM_TDB	

-	79	((coupled adj2 (line conductor trace microstrip stripline path)) and coupled adj2 (line conductor trace microstrip stripline path) with varactor) not (((coupled adj2 (line conductor trace microstrip stripline path)) and coupled adj2 (line conductor trace microstrip stripline path)) and pin)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:37
	25	(((coupled adj2 (line conductor trace microstrip stripline path)) and coupled adj2 (line conductor trace microstrip stripline path) with varactor) not (((coupled adj2 (line conductor trace microstrip stripline path)) and coupled adj2 (line conductor trace microstrip stripline path)) and 333/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:46
•	1	"4619001".PN.	USPAT	2003/08/22 12:38
-	1867	((333/164) or (333/138-140) or (333/156) or (333/160) or (333/161)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:47
-	352	(((333/164) or (333/138-140) or (333/156) or (333/160) or (333/161)).CCLS.) and coupl\$4 near3 (line conductor trace microstrip stripline path)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:48
-	29	((((333/164) or (333/138-140) or (333/156) or (333/160) or (333/161)).CCLS.) and coupl\$4 near3 (line conductor trace microstrip stripline path)) and (line conductor trace microstrip stripline path) with varactor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:55
-	99	coupled adj2 (line conductor trace microstrip stripline path) with varactor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:55 -
-	1432	(333/109-116).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 12:55
-	17	((333/109-116).CCLS.) and (line conductor trace microstrip stripline path) with varactor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/22 13:07

		(HOOGETOTH HO 4000 40" HO 4000 TO"	1.00.5	
-	23	("3305797" "3400342" "3422378"	USPAT	2003/08/22
		"3422438" "3423699" "3477028" "3477045" "3577028"		12:58
		"3479615" "3506930" "3555447" "3574769" "3574765" "3646467"		
		"3571762" "3571765" "3646467"		
		"3676803" "3768045" "3769610"		
		"3909751" "3928806" "3986147"		
		"4004255" "4028632" "4205282"		
		"4288763" "4301432").PN.		0000/00/00
-	9	3400342.URPN.	USPAT	2003/08/22
	48			13:03
•	46	coupler same parasitic adj capacit\$5	USPAT;	2003/08/22
			US-PGPUB;	13:15
			EPO; JPO;	
,			DERWENT;	
1	45		IBM_TDB	0000/00/00
•	45	coupled adj (line conductor path trace	USPAT;	2003/08/22
		microstrip stripline) same parasitic adj	US-PGPUB;	13:20
		capacit\$5	EPO; JPO;	
			DERWENT;	
	3		IBM_TDB	0000/00/00
-	3	coupled adj (line conductor path trace	USPAT;	2003/08/22
		microstrip stripline) with inherent\$ near3	US-PGPUB;	13:21
		capacit\$5	EPO; JPO;	
1			DERWENT;	
•		(/222/422 445) 2010) 1/ :/: 44	IBM_TDB	
-	28	((333/109-116).CCLS.) and (parasitic\$4	USPAT;	2003/08/22
		inherent\$4) near3 capacit\$5	US-PGPUB;	14:41
			EPO; JPO;	
			DERWENT;	
	24	microscope and above all abilities and	IBM_TDB	0000/00/00
-	21	microwave and phase adj shift\$4 and	USPAT;	2003/08/22
		embed\$4 near5 (substrate layer) and 333/\$.ccls.	US-PGPUB;	14:44
		- JJJ/ 孝. CCIS.	EPO; JPO;	
			DERWENT;	
	30	nhoco odi chifff and ombodé 4	IBM_TDB	2002/20/20
•	30	phase adj shift\$4 and embed\$4 near5	USPAT;	2003/08/22
		(substrate layer) and 333/\$.ccls.	US-PGPUB;	14:44
			EPO; JPO;	
			DERWENT;	-
_	9	/ phase edi chiff\$4 and such sd\$4	IBM_TDB	2002/00/22
•	9	(phase adj shift\$4 and embed\$4 near5	USPAT;	2003/08/22
		(substrate layer) and 333/\$.ccls.) not	US-PGPUB;	14:45
		(microwave and phase adj shift\$4 and	EPO; JPO;	
		embed\$4 near5 (substrate layer) and	DERWENT;	
_	305	333/\$.ccls.)	IBM_TDB	0000/00/00
•	305	phase adj shift\$4.ti. and (dielectric	USPAT;	2003/08/22
		insulating) adj (layer substrate)	US-PGPUB;	14:48
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	

	· .	1		0000/00/00
-	101	(phase adj shift\$4.ti. and (dielectric	USPAT;	2003/08/22
		insulating) adj (layer substrate)) and	US-PGPUB;	.14:46
		333/\$.ccls.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	13	phase adj shift\$4.ti. and (dielectric	USPAT;	2003/08/22
		insulating) adj (layer substrate) and	US-PGPUB;	14:50
		embed\$4	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	phase adj shift\$4.ti. and (dielectric	USPAT;	2003/08/22
		insulating) adj (layer substrate) and	US-PGPUB;	14:52
		"disposed in"	EPO; JPO;	
		•	DERWENT;	
			IBM_TDB	
_	130	"disposed in"	USPAT;	2003/08/22
			US-PGPUB;	14:51
			EPO; JPO;	1.7101
			DERWENT;	
			IBM_TDB	
_	102	phase adj shift\$4.ti. and (dielectric	USPAT;	2003/08/22
-	102	1 .	1	14:57
		insulating) adj (layer substrate) and	US-PGPUB;	14:57
		deposit\$4	EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	13	phase adj shift\$4.ti. and (dielectric	USPAT;	2003/08/22
		insulating) adj (layer substrate) with within	US-PGPUB;	14:58
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	9	phase adj shift\$4 and (dielectric insulating)	USPAT;	2003/08/22
		adj (layer substrate) with (within embed\$5)	US-PGPUB;	15:03
		and (((333/164) or (333/138-140) or (333/156)	EPO; JPO;	
		or (333/160) or (333/161)).CCLS.)	DERWENT;	
			IBM_TDB	
-	58	(dac " d adj a" digital adj analog) with	USPAT;	2003/08/22
		control\$4 with varactor	US-PGPUB;	15:10 ·
		·	EPO; JPO;	
			DERWENT;	
	,		IBM_TDB	
•	169	second adj coupl\$4 adj (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip)	US-PGPUB;	15:11
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3	second adj coupl\$4 adj (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) with (US-PGPUB;	15:12
		varactor variable adj capacitance)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
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-	3	second adj coupl\$4 adj (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) with (US-PGPUB;	15:13
		varactor variable adj capacit\$6)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	21	333/\$.ccls. and coupled adj (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) with (US-PGPUB;	15:18
		varactor variable adj capacit\$6)	EPO; JPO;	
:			DERWENT;	
			IBM_TDB	
-	108	333/\$.ccls. and coupled adj (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) and (US-PGPUB;	15:19
		varactor variable adj capacit\$6)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	326	333/\$.ccls. and coupled adj3 (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) and (US-PGPUB;	15:20
		varactor variable adj capacit\$6)	EPO; JPO;	
			DERWENT;	
		,	IBM TDB	
-	59	333/\$.ccls. and coupled adj3 (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) with (US-PGPUB;	15:20
		varactor variable adj capacit\$6)	EPO; JPO;	13.20
		variation variable auj capacityo)	1 '	
			DERWENT;	
	20	(222/\$ colo and counted edit / line two c	IBM_TDB	0000/00/00
-	38	(333/\$.ccls. and coupled adj3 (line trace	USPAT;	2003/08/22
		conductor path stripline microstrip) with (US-PGPUB;	15:41
		varactor variable adj capacit\$6)) not	EPO; JPO;	
		(333/\$.ccls. and coupled adj (line trace	DERWENT;	
		conductor path stripline microstrip) with (IBM_TDB	
	_	varactor variable adj capacit\$6))		
-	5	("3864824" "4121182" "4283694"	USPAT	2003/08/22
		"4383227" "4468644").PN.		15:21
-	3234	equalizer with delay	USPAT;	2003/08/22
			US-PGPUB;	15:42
			EPO; JPO;	,
			DERWENT;	
			IBM_TDB	
-	472	equalizer with delay and 333/\$.ccls.	USPAT;	2003/08/22
			US-PGPUB;	15:42
			EPO; JPO;	
	}	·	DERWENT;	:
			IBM_TDB	
-	362	equalizer near5 delay and 333/\$.ccls.	USPAT;	2003/08/22
			US-PGPUB;	15:43
		, ·	EPO; JPO;	
			DERWENT;	
			IBM_TDB	·
-	373	equalizer near5 delay\$4 and 333/\$.ccls.	USPAT;	2003/08/22
			US-PGPUB;	15:45
		·	EPO; JPO;	10.70
			DERWENT;	
			1	
L	L		IBM_TDB	

•	226	(equalizer near5 delay\$4 and 333/\$.ccls.)	USPAT;	2003/08/22
		and equalizer.ti.	US-PGPUB;	15:43
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	18	equalizer near5 delays and 333/\$.ccls.	USPAT;	2003/08/24
			US-PGPUB;	13:37
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	